# **General Purpose Transistors**

**PNP Silicon** 



## 2N4036 2N4037



#### MAXIMUM RATINGS

Rating	Symbol	2N4036	2N4037	Unit
Collector-Emitter Voltage	VCEO	-65	-40	Vdc
Collector-Base Voltage	V <sub>CBO</sub>	-90	-60	Vdc
Emitter-Base Voltage	VEBO	-7.0	-7.0	Vdc
Base Current	ΙB	-0	Adc	
Collector Current — Continuous	IC	-1.0		Adc
Continuous Power Dissipation at or Below T <sub>C</sub> = 25°C Linear Derating Factor	PD	5.0 28.6	5.0 28.6	Watts mW/°C
Continuous Power Dissipation at or Below T <sub>A</sub> = 25°C Linear Derating Factor	PD	1.0 5.72	1.0 5.72	Watts mW/°C
Operating and Storage Junction Temperature Range	Т <sub>Ј</sub> , Т <sub>stg</sub>	-65 to +200		°C
Lead Temperature 1/16" from Case for 10 Seconds	т∟	230		°C

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	2N4036	2N4037	Unit
Thermal Resistance, Junction to Case	$R_{ hetaJC}$	35	35	°C/W

**ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$  unless otherwise noted)

Characteristic		Symbol	Min	Max	Unit
OFF CHARACTERISTICS					
Collector-Emitter Sustaining Voltage(1) ( $I_C = -100 \text{ mAdc}, I_B = 0$ )	2N4036 2N4037	V <sub>CEO(sus)</sub>	-65 -40		Vdc
Collector-Base Breakdown Voltage (I <sub>C</sub> = -0.1 mAdc)	2N4037	V(BR)CBO	-60	—	Vdc
Collector Cutoff Current ( $V_{CE} = -85$ Vdc, $V_{EB} = -1.5$ Vdc) ( $V_{CE} = -30$ Vdc, $V_{EB} = -1.5$ Vdc, $T_{C} = 150^{\circ}$ C)	2N4036 2N4037	ICEX		-0.1 -100	mAdc
Collector Cutoff Current $(V_{CB} = -90 \text{ Vdc}, I_E = 0)$ $(V_{CB} = -60 \text{ Vdc}, I_E = 0)$	2N4036 2N4037	СВО		-1.0 -0.25	μAdc
Emitter Cutoff Current $(V_{EB} = -7.0 \text{ Vdc}, I_{C} = 0)$ $(V_{EB} = -5.0 \text{ Vdc}, I_{C} = 0)$	2N4036 2N4037	IEBO		-10 -1.0	μAdc

1. Pulse Test: Pulse Width  $\leq$  300  $\mu s,$  Duty Cycle  $\leq$  2.0%.



#### 2N4036 2N4037

### **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ unless otherwise noted) (Continued)

Characteristic		Symbol	Min	Max	Unit
ON CHARACTERISTICS		•			
DC Current Gain (I <sub>C</sub> = -0.1 mAdc, V <sub>CE</sub> = -10 Vdc)	2N4036	hFE	20	_	_
$(I_{C} = -1.0 \text{ mAdc}, V_{CE} = -10 \text{ Vdc})$ $(I_{C} = -150 \text{ mAdc}, V_{CE} = -10 \text{ Vdc})^{(1)}$	2N4037 2N4036 2N4037		15 40 50	— 140 250	
$(I_{C} = -150 \text{ mAdc}, V_{CE} = -2.0 \text{ Vdc})^{(1)}$ $(I_{C} = -500 \text{ mAdc}, V_{CE} = -10 \text{ Vdc})^{(1)}$	2N4036 2N4036		20 20	200 —	
Collector-Emitter Saturation Voltage <sup>(1)</sup> ( $I_C = -150$ mAdc, $I_B = -15$ mAdc)	2N4036 2N4037	VCE(sat)	_	-0.65 -1.4	Vdc
Base-Emitter Saturation Voltage <sup>(1)</sup> (I <sub>C</sub> = -150 mAdc, I <sub>B</sub> = -15 mAdc)	2N4036	VBE(sat)	-	-1.4	Vdc
Base-Emitter On Voltage <sup>(1)</sup> (I <sub>C</sub> = -150 mAdc, V <sub>CE</sub> = -10 Vdc)	2N4037	V <sub>BE(on)</sub>	-	-1.5	Vdc
SMALL-SIGNAL CHARACTERISTICS					
Collector–Base Capacitance (V <sub>CB</sub> = –10 Vdc, f = 1.0 MHz)	2N4037	C <sub>cb</sub>	_	30	pF
Current Gain — High Frequency (I <sub>C</sub> = -50 mAdc, V <sub>CE</sub> = -10 Vdc, f = 20 MHz)	2N4036 2N4037	h <sub>fe</sub>	3.0 3.0	 10	
SWITCHING CHARACTERISTICS					
Rise Time (I <sub>B1</sub> = -15 mAdc)	2N4036	tr	_	70	ns
Storage Time (I <sub>B2</sub> = -15 mAdc)	2N4036	t <sub>s</sub>	-	600	ns
Fall Time (I <sub>B2</sub> = –15 mAdc)	2N4036	tf	_	100	ns
Turn–On Time (I <sub>B1</sub> = I <sub>B2</sub> )	2N4036	ton	_	110	ns
Turn–Off Time (I <sub>B1</sub> = I <sub>B2</sub> )	2N4036	toff	_	700	ns

1. Pulse Test: Pulse Width  $\leq$  300 µs, Duty Cycle  $\leq$  2.0%.

#### 2N4036 2N4037



#### PACKAGE DIMENSIONS



NOTES

 DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

2. CONTROLLING DIMENSION: INCH.

 DIMENSION J MEASURED FROM DIMENSION A MAXIMUM.

4. DIMENSION B SHALL NOT VARY MORE THAN 0.25 (0.010) IN ZONE R. THIS ZONE

5. DIMENSION F APPLIES BETWEEN DIMENSION P AND L. DIMENSION D APPLIES BETWEEN DIMENSION P AND L. DIMENSION D APPLIES BETWEEN DIMENSION L AND K MINIMUM. LEAD DIAMETER IS UNCONTROLLED IN DIMENSION P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIN	IETERS	
DIM	MIN	MAX	MIN	MAX	
Α	0.335	0.370	8.51	9.39	
В	0.305	0.335	7.75	8.50	
С	0.240	0.260	6.10	6.60	
D	0.016	0.021	0.41	0.53	
Е	0.009	0.041	0.23	1.04	
F	0.016	0.019	0.41	0.48	
G	0.200 BSC		5.08 BSC		
Н	0.028	0.034	0.72	0.86	
J	0.029	0.045	0.74	1.14	
K	0.500	0.750	12.70	19.05	
L	0.250		6.35		
Μ	45 °	45 °BSC		45°BSC	
Ρ		0.050		1.27	
R	0.100		2.54		

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